



April 1992 Revised May 2005 '4ABT16244 16-Bit Buffer/Line Driver with 3-STATE Outputs

74ABT16244 16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

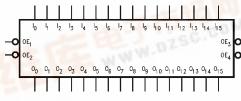
Features

- Separate control logic for each nibble
- 16-bit version of the ABT244
- Outputs sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications Output switching specified for both 50 pF and
- 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description			
74ABT16244CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide			
74ABT16244CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide			
Devices are also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.					

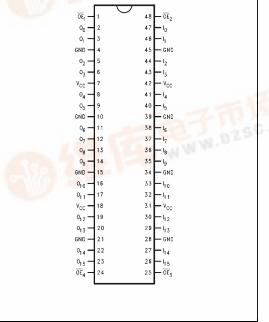
Logic Symbol



Pin Descriptions

Pin Names	Description
OEn	Output Enable Inputs (Active LOW)
I ₀ –I ₁₅	Inputs COMPANY
0 ₀ -0 ₁₅	Outputs

Connection Diagram





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Truth Tables						
uts	Outputs					
I ₀ –I ₃	0 ₀ –0 ₃					
L	L					
н	н					
Х	Z					
uts	Outputs					
I ₄ –I ₇	0 ₄ –0 ₇					
L	L					
н	н					
Х	Z					
uts	Outputs					
I ₈ –I ₁₁	0 ₈ –0 ₁₁					
L	L					
н	н					
Х	Z					
outs	Outputs					
I ₁₂ –I ₁₅	0 ₁₂ -0 ₁₅					
L	L					
н	н					
х	Z					
	I_0-I_3 L H X uts I_4-I_7 L H X uts I_8-I_11 L H X uts I_8-I_11 L H X uts I_8-I_11 L H X uts I_12-I_15 L H					

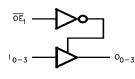
H = HIGH Voltage Level L = LOW Voltage Level

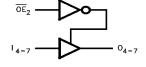
X = Immaterial Z = High Impedance

Functional Description

The ABT16244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagram





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Absolute Maximum Ratings(Note 1)

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	–55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	-0.5V to 5.5V
in the HIGH State	-0.5V to V _{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I _{OL} (mA)
DC Latchup Source Current	–500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	-40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Par	ameter	Min	Тур	Max	Units	V _{cc}	Conditions
VIH	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
VIL	Input LOW Voltage				0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Vo	Itage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage		2.5			V	Min	I _{OH} = -3 mA
			2.0			V	Min	I _{OH} = -32 mA
V _{OL}	Output LOW Voltage				0.55	V	Min	I _{OL} = 64 mA
IIH	Input HIGH Current				1 1	μA	Max	V _{IN} = 2.7V (Note 3) V _{IN} = V _{CC}
I _{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V _{IN} = 7.0V
IIL	Input LOW Current				-1 -1	μA	Max	V _{IN} = 0.5V (Note 3) V _{IN} = 0.0V
V _{ID}	Input Leakage Test		4.75			V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OZH}	Output Leakage Curre	ent			10	μA	0 – 5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I _{OZL}	Output Leakage Curre	ent			-10	μA	0 – 5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
I _{OS}	Output Short-Circuit C	urrent	-100		-275	mA	Max	$V_{OUT} = 0.0V$
I _{CEX}	Output HIGH Leakage	Current			50	μA	Max	$V_{OUT} = V_{CC}$
I _{ZZ}	Bus Drainage Test				100	μΑ	0.0	V _{OUT} = 5.5V All Other Pins GND
I _{CCH}	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I _{CCL}	Power Supply Current				60	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current				2.0	mA	Max	OE _n = V _{CC} All Others at V _{CC} or GND
I _{CCT}	Additional I _{CC} /Input	Outputs Enabled			2.5	mA		$V_{I} = V_{CC} - 2.1V$
		Outputs 3-STATE			2.5	mA	Max	Enable Input V _I = V _{CC} - 2.1
		Outputs 3-STATE			50	μA		Data Input $V_I = V_{CC} - 2.1V$ All Others at V_{CC} or GND
ICCD	Dynamic I _{CC} (Note 3)	No Load			0.1	mA/ MHz	Max	Outputs Open, $\overline{OE}_n = GND$ One Bit Toggling, 50% Duty Cycle

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DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Units	v _{cc}	Conditions C _L = 50 pF, R _L = 500 Ω
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}		0.4	0.7	V	5.0	$T_A = 25 \degree C$ (Note 4)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-1.3	-1.0		V	5.0	$T_A = 25 \degree C$ (Note 4)
V _{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.0		V	5.0	$T_A = 25 \degree C$ (Note 5)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.4		V	5.0	T _A = 25°C (Note 6)
V _{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	$T_A = 25^{\circ}C$ (Note 6)

Note 4: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested. Note 6: Max number of data inputs (n) switching. n-1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{ILD}).

Note b: Max number of data inputs (n) switching. n-1 inputs switching uv to 3V. input-under-test switching: 3V to threshold (V_{ILD}), UV to threshold (V_{ILD}), UV to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter		T _A =+25°C V _{CC} =+5V C _L = 50 pF		V _{CC} = 4	C to +85°C .5V–5.5V 50 pF	Units
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation	1.0	2.3	3.9	1.0	3.9	
t _{PHL}	Delay Data to Outputs	1.0	2.7	3.9	1.0	3.9	ns
t _{PZH}	Output Enable	1.5	3.5	6.3	1.5	6.3	
t _{PZL}	Time	1.5	3.5	6.3	1.5	6.3	ns
t _{PHZ}	Output Disable	1.0	4.2	6.7	1.0	6.7	ns
t _{PLZ}	Time	1.0	3.2	6.7	1.0	6.7	115

Extended AC Electrical Characteristics

Symbol	Parameter	-40°C to +85°C V _{CC} = 4.5V-5.5V C _L = 50 pF 16 Outputs Switching (Note 7)		V _{CC} = 4 C _L = 2 1 Output	C to +85°C .5V–5.5V 250 pF Switching te 8)	$V_{CC} = 4$ $C_L = 2$ 16 Outputs	C to +85°C .5V–5.5V 250 pF s Switching te 9)	Units	
		Min	Тур	Мах	Min	Max	Min	Max	
f _{TOGGLE}	Max Toggle Frequency		100						MHz
t _{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.0	ns
t _{PHL}	Data to Outputs	1.5		5.3	1.5	6.0	2.5	8.0	115
t _{PZH}	Output Enable Time	1.5		6.5	2.5	7.8	2.5	9.5	ns
t _{PZL}		1.5		6.5	2.5	7.8	2.5	8.5	115
t _{PHZ}	Output Disable Time	1.0		6.7	(Not	o 10)	(Not	0.10)	ns
t _{PLZ}		1.0		6.7	(Note 10)		(Note 10)		115

Note 7: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 8: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 9: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 10: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Symbol	Parameter	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V-5.5V$ $C_{L} = 50 \text{ pF}$ 16 Outputs Switching (Note 11)	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V-5.5V$ $C_{L} = 250 \text{ pF}$ 16 Outputs Switching (Note 12)	Units
+	Pin to Pin Skew	Мах	Max	
t _{OSHL} (Note 13)	HL Transitions	1.0	1.5	ns
t _{OSLH} (Note 13)	Pin to Pin Skew LH Transitions	1.0	1.5	ns
t _{PS} (Note 14)	Duty Cycle LH–HL Skew	1.5	1.5	ns
t _{OST} (Note 13)	Pin to Pin Skew LH/HL Transitions	1.7	2.0	ns
t _{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.0	2.5	ns

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 12: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

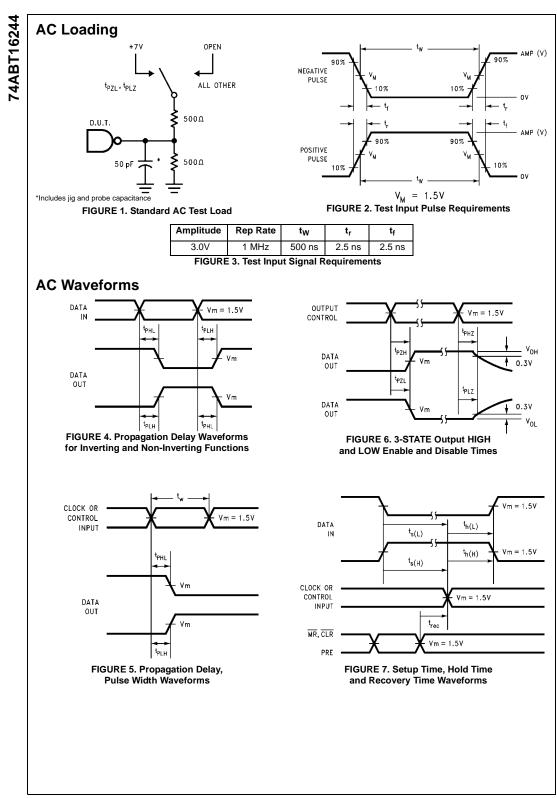
Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 14: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested. Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Тур	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	5.0	pF	$V_{CC} = 5.0V$
C _{OUT} (Note 16)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 16: C_{OUT} is measured at frequency f = 1 MHz; per MIL STD-883, Method 3012.



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